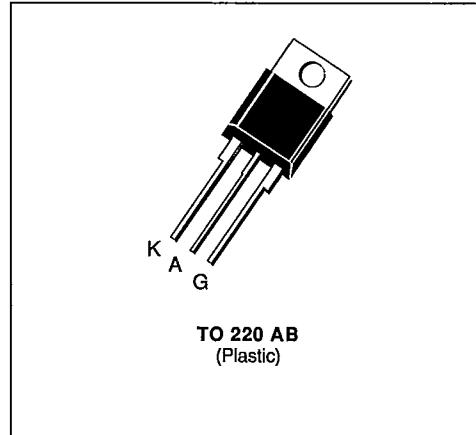


T.25-13  
**THYRISTORS**

- GLASS PASSIVATED CHIP
- POSSIBILITY OF MOUNTING ON PRINTED CIRCUIT
- AVAILABLE IN NON-INSULATED VERSION -> TYN SERIES OR IN INSULATED VERSION -> TXN SERIES (INSULATING VOLTAGE 2500 VRMS)
- UL RECOGNIZED FOR TXN SERIES (E81734)



### DESCRIPTION

SCR's designed for motor control, heating controls, power supplies...

### ABSOLUTE RATINGS (limiting values)

| Symbol             | Parameter   | Value                    | Unit      |
|--------------------|---|--------------------------|-----------|
| $I_{T(RMS)}$       | RMS on-state Current (1)  | 4                        | A         |
| $I_{T(AV)}$        | Mean on-state Current (1)   | 2.5                      | A         |
| $I_{tSM}$          | Non Repetitive Surge Peak on-state Current ( $T_j$ , initial = 25 °C) (2) | 73                       | A         |
|                    | $t = 8.3$ ms  | 70                       |           |
| $I^2t$             | $I^2t$ Value for Fusing   | 24.5                     | $A^2s$    |
| $di/dt$            | Critical Rate of Rise of on-state Current (3)                             | 50                       | $A/\mu s$ |
| $T_{stg}$<br>$T_j$ | Storage and Operating Junction Temperature Range                          | -40 to 110<br>-40 to 110 | °C<br>°C  |

| Symbol                 | Parameter                             | TXN/TYN |     |     |     |     |     |      | Unit |
|------------------------|---------------------------------------|---------|-----|-----|-----|-----|-----|------|------|
|                        |                                       | 054     | 104 | 204 | 404 | 604 | 804 | 1004 |      |
| $V_{DRM}$<br>$V_{RRM}$ | Repetitive Peak off-state Voltage (4) | 50      | 100 | 200 | 400 | 600 | 800 | 1000 | V    |

(1) Single phase circuit, 180° conduction angle.

(2) Half sine wave.

(3)  $I_g = 150$  mA    $di/dt = 1 A/\mu s$ .

(4)  $T_j = 110$  °C.

### THERMAL RESISTANCES

| Symbol         | Parameter              | Value | Unit |
|----------------|------------------------|-------|------|
| $R_{th (j-c)}$ | Junction-case for D.C. | 5     | °C/W |
| $R_{th (j-a)}$ | Junction-ambient       | 60    | °C/W |

TXN/TYN 054 → 1004

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## GATE CHARACTERISTICS (maximum values)

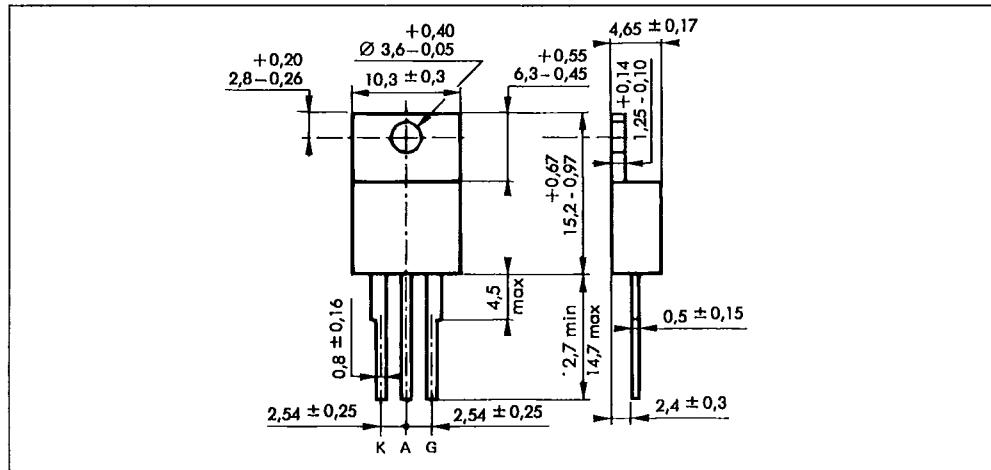
 $P_{GM} = 20 \text{ W}$  ( $t_p = 20 \mu\text{s}$ ) $I_{FGM} = 2 \text{ A}$  ( $t_p = 20 \mu\text{s}$ ) $V_{RGM} = 5 \text{ V}$  $P_G(\text{AV}) = 0.5 \text{ W}$  $V_{FGM} = 15 \text{ V}$  ( $t_p = 20 \mu\text{s}$ )

## ELECTRICAL CHARACTERISTICS

| Symbol    | Test Conditions   |   |  | Min. | Typ. | Max. | Unit                   |
|-----------|---|---|--|------|------|------|------------------------|
| $I_{GT}$  | $T_j = 25^\circ\text{C}$<br>Pulse Duration > 20 $\mu\text{s}$                     | $V_D = 12 \text{ V}$                                      | $R_L = 33 \Omega$  |      |      | 15   | mA                     |
| $V_{GT}$  | $T_j = 25^\circ\text{C}$<br>Pulse Duration > 20 $\mu\text{s}$                     | $V_D = 12 \text{ V}$                                      | $R_L = 33 \Omega$  |      |      | 1.5  | V                      |
| $V_{GD}$  | $T_j = 110^\circ\text{C}$   | $V_D = V_{DRM}$   | $R_L = 3.3 \text{ k}\Omega$                                | 0.2  |      |      | V                      |
| $I_H$     | $T_j = 25^\circ\text{C}$  | $I_T = 100 \text{ mA}$                                    | Gate Open  |      |      | 30   | mA                     |
| $I_L$     | $T_j = 25^\circ\text{C}$<br>Pulse Duration > 20 $\mu\text{s}$                     | $V_D = 12 \text{ V}$                                      | $I_G = 30 \text{ mA}$                                      |      | 50   |      | mA                     |
| $V_{TM}$  | $T_j = 25^\circ\text{C}$  | $I_{TM} = 8 \text{ A}$                                    | $t_p = 10 \text{ ms}$                                      |      |      | 1.8  | V                      |
| $I_{DRM}$ | $V_{DRM}$ Specified   |   | $T_j = 25^\circ\text{C}$                                   |      |      | 0.01 | mA                     |
|           |   |   | $T_j = 110^\circ\text{C}$                                  |      |      | 1    |                        |
| $I_{RRM}$ | $V_{RRM}$ Specified   |   | $T_j = 25^\circ\text{C}$                                   |      |      | 0.01 | mA                     |
|           |   |   | $T_j = 110^\circ\text{C}$                                  |      |      | 1    |                        |
| $t_{gt}$  | $T_j = 25^\circ\text{C}$<br>$I_G = 40 \text{ mA}$                                 | $V_D = V_{DRM}$<br>$dI_G/dt = 0.45 \text{ A}/\mu\text{s}$ | $I_T = 8 \text{ A}$  |      | 2    |      | $\mu\text{s}$          |
| $t_q$     | $T_j = 110^\circ\text{C}$<br>$V_D = 67\% V_{DRM}$<br>Gate Open                    | $I_T = 8 \text{ A}$<br>$dI/dt = 30 \text{ A}/\mu\text{s}$ | $V_R = 25 \text{ V}$<br>$dv/dt = 50 \text{ V}/\mu\text{s}$ |      | 70   |      | $\mu\text{s}$          |
| $dv/dt^*$ | $T_j = 110^\circ\text{C}$<br>Linear Slope up to $V_D = 67\% V_{DRM}$<br>Gate Open |   |  | 200  |      |      | $\text{V}/\mu\text{s}$ |

\* For higher guaranteed values, please consult us.

## PACKAGE MECHANICAL DATA : TO 220 AB Plastic



Cooling method : by conduction (method C)

Marking : type number

Weight : 2 g

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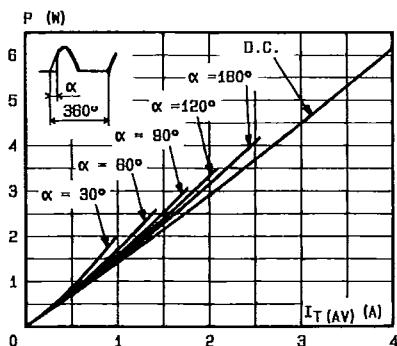


Fig.1 - Maximum mean power dissipation versus mean on-state current.

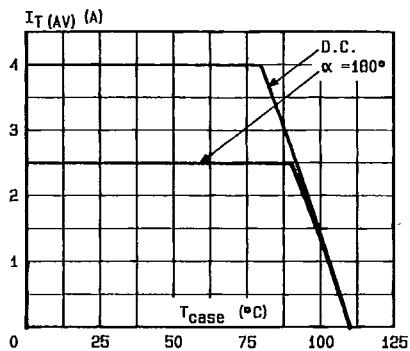


Fig.3 - Mean on-state current versus case temperature.

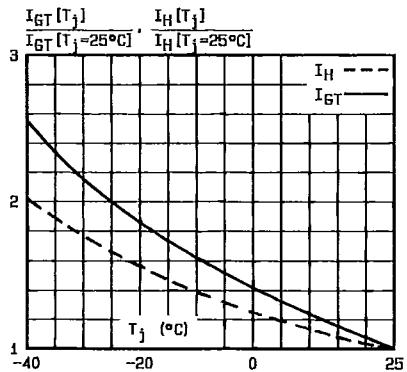


Fig.5 - Relative variation of gate trigger current and holding current versus junction temperature.

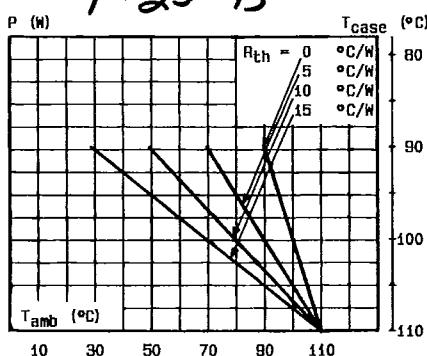


Fig.2 - Correlation between maximum mean power dissipation and maximum allowable temperatures (T\_amb and T\_case) for different thermal resistances heatsink + contact.

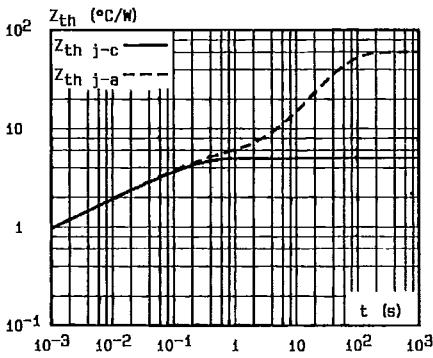


Fig.4 - Thermal transient impedance junction to case and junction to ambient versus pulse duration.

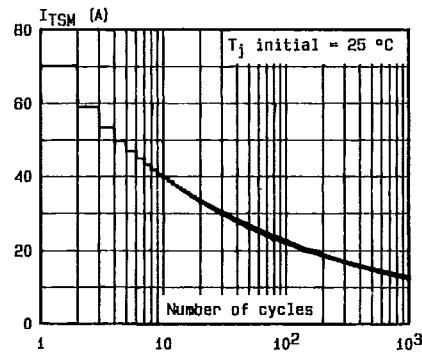


Fig.6 - Non repetitive surge peak on-state current versus number of cycles.

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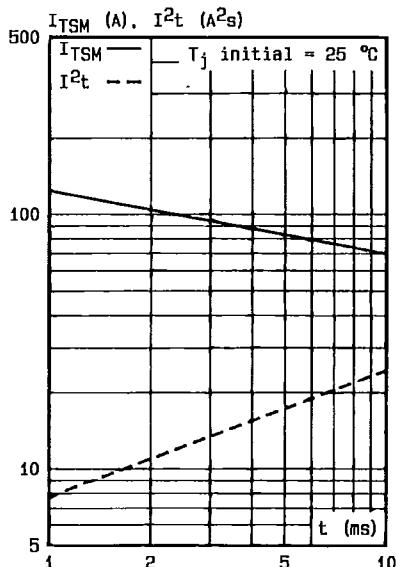


Fig.7 - Non repetitive surge peak on-state current for a sinusoidal pulse with width :  $t \leq 10$  ms, and corresponding value of  $I^2t$ .

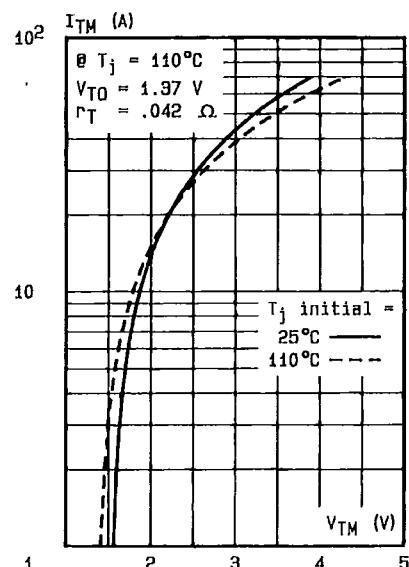


Fig.8 - On-state characteristics (maximum values).